



MMIC BALUN

RF Transformer Die

MTX2-183-D+

50Ω 2000 to 18000 MHz

THE BIG DEAL

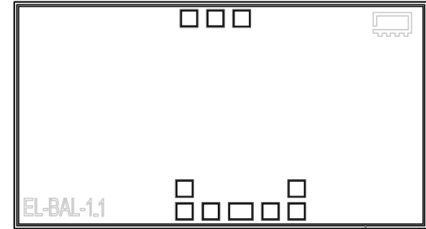
- Wideband, 2000 to 18000 MHz
- Low insertion loss, 1.4 dB typ. (above theoretical) at 10000 MHz
- Excellent Common Mode Rejection, 33 dB typ.

APPLICATIONS

- Cellular Infrastructure
- Instrumentation
- RADAR
- Satcom
- Electronic Warfare
- Mixers & Modulators

PRODUCT OVERVIEW

Mini-Circuits MTX2-183-D+ is a wideband MMIC balun transformer die with an impedance ratio of 1:2 applicable for a wide range of applications from 2000 to 18000 MHz. Fabricated using GaAs HBT process technology, this model provides outstanding repeatability with low insertion loss, low amplitude unbalance, low phase unbalance, and excellent common mode rejection.



+RoHS Compliant
 The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

SEE ORDERING INFORMATION ON THE LAST PAGE

KEY FEATURES

Feature	Advantages
Wideband, 2000 to 18000 MHz	MTX2-183-D+ supports a broad variety of applications including instrumentation, WLAN, WiMAX, WiBRO, ISM, radar and more.
Low insertion loss • 1.4 dB typ. (above theoretical) at 7000 MHz	Enables excellent signal power transmission from input to output.
Low unbalance • 0.4 dB typ. amplitude unbalance • 1.2° typ. phase unbalance	Low unbalance can improve a system's electromagnetic compatibility by rejecting unwanted common-mode noise.
Excellent Common Mode Rejection • 33 dB typ.	Enables rejection of undesired signals
Unpackaged Die	Enables the user to integrate the balun directly into hybrids.

REV. OR
 ECO-010992
 MTX2-183-D+
 MCLNY
 211207



**ELECTRICAL SPECIFICATIONS¹ AT 25°C, 50Ω, UNLESS OTHERWISE NOTED.**

Parameter	Frequency (MHz)	Min.	Typ.	Max.	Unit
Impedance Ratio (secondary / primary)			2		
Frequency Range		2000		18000	MHz
Insertion Loss (Above 3 dB Theoretical)	2000-4000		2.1		dB
	4000-14000		1.4		
	14000-18000		2.5		
Amplitude Unbalance	2000-4000		0.5		dB
	4000-14000		0.2		
	14000-18000		0.9		
Phase Unbalance ²	2000-4000		1.7		Degree
	4000-14000		1.4		
	14000-18000		2.8		
Common Mode Rejection Ratio	2000-4000		28		dB
	4000-14000		37		
	14000-18000		25		
Input Return Loss	2000-4000		8		dB
	4000-14000		13		
	14000-18000		12		

1. Measured on X-Microwave Die Characterization test board.

2. Relative to 180°

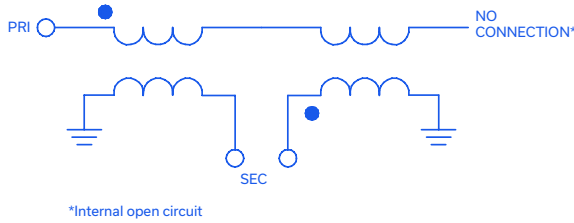
MAXIMUM RATINGS³

Parameter	Ratings
Operating Temperature	-40°C to 85°C
Input RF Power	33 dBm at 25°C

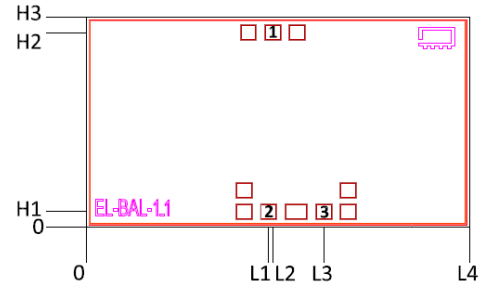
3. Permanent damage may occur if any of these limits are exceeded.



SIMPLIFIED SCHEMATIC



BONDING PAD POSITION



PAD DESCRIPTION

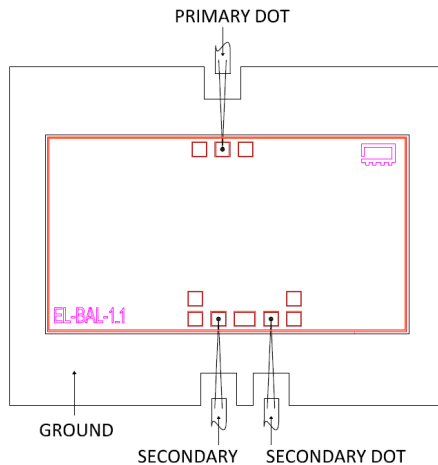
Pad Number	Description
1	Primary Dot
2	Secondary
3	Secondary Dot

DIE DIMENSIONS IN μm


L1	L2	L3	L4	H1	H2	H3
1128	1154	1470	2370	97	1206	1300

Thickness	Die Size	Pad Size 1, 2 & 3
100	2370 x 1300	89 x 89

ASSEMBLY DIAGRAM



ASSEMBLY PROCEDURE

- Storage**
 Dice should be stored in a dry nitrogen purged desiccators or equivalent.
- 
ESD
 MMIC GaAs HBT RF Transformer dice are susceptible to electrostatic and mechanical damage. Die are supplied in antistatic protected material, which should be opened in clean room conditions at an appropriately grounded anti-static workstation. Devices need careful handling using correctly designed collets, vacuum pickup tips or sharp antistatic tweezers to deter ESD damage to dice.
- Die Attach**
 The die mounting surface must be clean and flat. Using conductive silver filled epoxy, recommended epoxies are Ablestik 84-1 LMISR4 or equivalents. Apply sufficient epoxy to meet required epoxy bond line thickness, epoxy fillet height and epoxy coverage around total die periphery. Parts shall be cured in a nitrogen filled atmosphere per manufacturer's cure condition. It is recommended to use antistatic die pick up tools only.
- Wire Bonding**
 Bond pad openings in the surface passivation above the bond pads are provided to allow wire bonding to the dice gold bond pads. Thermosonic bonding is used with minimized ultrasonic content. Bond force, time, ultrasonic power and temperature are all critical parameters. Suggested wire is pure gold, 1 mil diameter. Bonds must be made from the bond pads on the die to the package or substrate. All bond wires should be kept as short as low as reasonable to minimize performance degradation due to undesirable series inductance.



ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASH BOARD.

Performance Data	Data Table	
	Swept Graphs	
	S-Parameter (S3P Files) Data Set with and without port extension(.zip file)	
Case Style	Die	
Die Ordering and packaging information	Quantity, Package Small, Gel - Pak: 5,10,50,100 KGD* Medium†, Partial wafer: KGD*<672	Model No. MTX2-183-DG+ MTX2-183-DP+
	†Available upon request contact sales representative Refer to AN-60-067	
Environmental Ratings	ENV80	

*Known Good Dice ("KGD") means that the dice are taken from PCM good wafer and visually inspected. While this is not definitive, it does help to provide a higher degree of confidence that dice are capable of meeting typical RF electrical parameters specified by Mini-Circuits.

NOTES

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
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RF Transformer Die

MTX2-183-D+

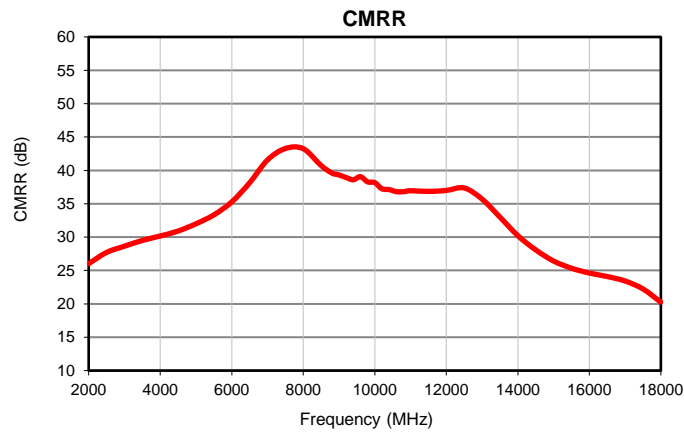
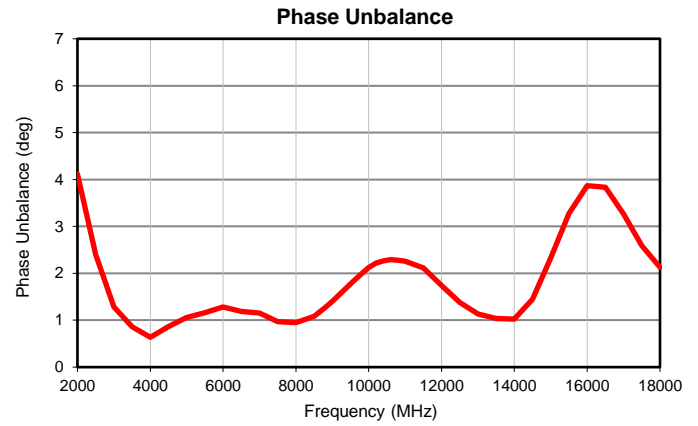
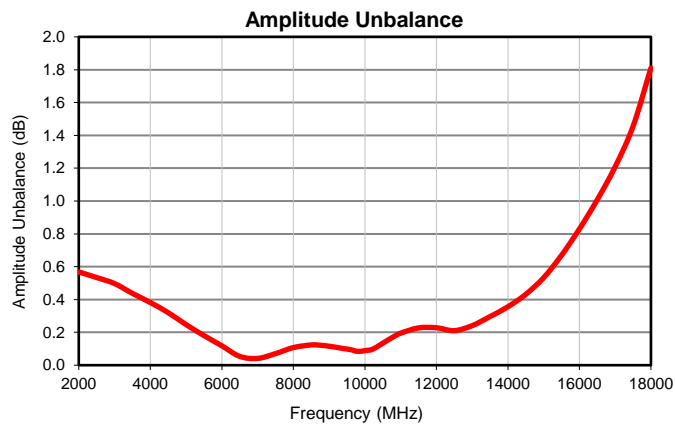
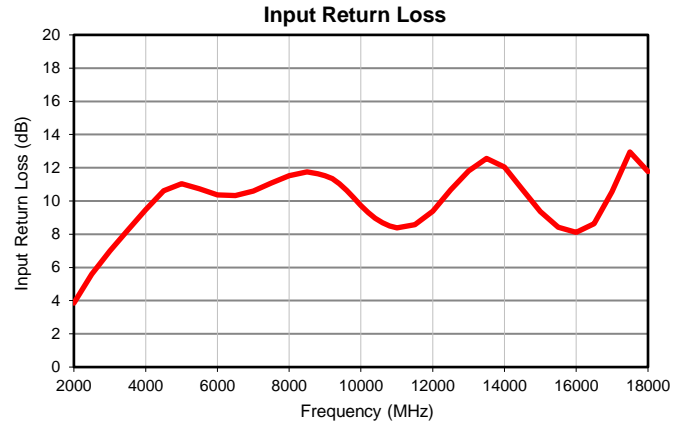
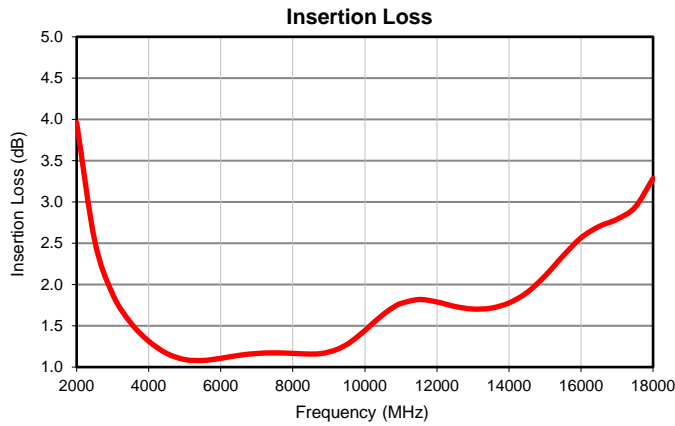
Typical Performance Data

FREQUENCY (MHz)	INSERTION LOSS (dB)	INPUT RETURN LOSS (dB)	AMPLITUDE UNBALANCE (dB)	PHASE UNBALANCE ⁽¹⁾ (deg.)	CMRR (dB)
2000	3.96	3.85	0.57	4.12	26.02
2500	2.53	5.59	0.53	2.40	27.71
3000	1.88	7.00	0.50	1.28	28.64
3500	1.54	8.24	0.44	0.86	29.50
4000	1.31	9.47	0.38	0.64	30.17
4500	1.17	10.61	0.32	0.87	30.91
5000	1.09	11.04	0.25	1.06	32.00
5500	1.08	10.73	0.18	1.16	33.33
6000	1.11	10.38	0.12	1.28	35.28
6500	1.14	10.33	0.05	1.19	38.14
7000	1.16	10.60	0.04	1.16	41.56
7500	1.17	11.07	0.07	0.97	43.28
8000	1.17	11.52	0.11	0.95	43.25
8500	1.16	11.75	0.12	1.08	40.73
8800	1.16	11.64	0.12	1.27	39.61
9000	1.18	11.52	0.12	1.40	39.32
9200	1.21	11.36	0.11	1.55	38.93
9400	1.25	11.04	0.10	1.70	38.60
9600	1.30	10.64	0.10	1.85	39.06
9800	1.37	10.19	0.08	1.99	38.28
10000	1.44	9.73	0.09	2.12	38.17
10200	1.52	9.31	0.10	2.22	37.24
10400	1.60	8.96	0.12	2.27	37.13
10600	1.67	8.69	0.15	2.29	36.82
10800	1.73	8.49	0.17	2.28	36.81
11000	1.77	8.39	0.20	2.26	36.96
11500	1.82	8.58	0.23	2.12	36.85
12000	1.79	9.38	0.23	1.74	36.99
12500	1.73	10.68	0.21	1.38	37.38
13000	1.70	11.82	0.24	1.13	35.70
13500	1.71	12.56	0.30	1.04	33.00
14000	1.78	12.05	0.36	1.02	30.23
14500	1.90	10.69	0.43	1.44	28.09
15000	2.10	9.36	0.53	2.33	26.42
15500	2.35	8.42	0.67	3.28	25.34
16000	2.57	8.11	0.83	3.87	24.62
16500	2.70	8.62	1.01	3.84	24.10
17000	2.79	10.56	1.21	3.26	23.42
17500	2.94	12.95	1.46	2.58	22.23
18000	3.28	11.77	1.81	2.13	20.26

⁽¹⁾ Relative to 180°



Typical Performance Data



All Mini-Circuits products are manufactured under exacting quality assurance and control standards, and are capable of meeting published specifications after being subjected to any or all of the following physical and environmental test.

Specification	Test/Inspection Condition	Reference/Spec
Operating Temperature	-40° to 85° C or -40° to 105° C or -55° to 105° C or -45° to 105° C Ambient Environment	Refer to Individual Model Data Sheet
Storage Environment (Die)	-65° to 150°C	Individual Model Data Sheet
Storage Environment(Packaging)	-40° to 70°C and 40 to 60% humidity (In Factory Shipped Package)	